SUPERCONDUCTING TRANSITION IN "BAD" METALS

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Field-induced ...



EXPERIMENTAL SUMMARY

Materials

Ultrathin films (Bi, Be,...)

InO_x a-Mo_xSi_{1-x} a-MoGe Nd_{2-x}Ce_xCuO_{4+y} { A.M. Goldman et al (1989, 1993) E.Bielejec and W.Wu (2002) J. A. Chervenak and J. M. Valles, Jr (2000) { A.F. Hebard and M.A. Paalanen (1990) V.F. Gantmakher et al. (1998, 2000) S. Okuma, et al. (1998) A.Yazdani and A.Kapitulnik (1995) { S. Tanda et al. (1992) V.F. Gantmakher et al. (2003) T.I. Baturina et al. (2002)

Common features

1. Fan-shaped structure of R(T) curves

TiN_x

- 2. Negative magnetoresistance in high fields
- 3. Scaling (??)

Superconductor-insulator transition in ultrathin Bi films



 $d < d_c$: Insulator

There are no clear data about the high-field magnetoresistance in ultrathin films

 $d > d_c$: Superconductor

D.B.Haviland, Y.Liu, and A.M.Goldman (1989)

Fan-shaped curves high resistivity

V.F. Gantmakher et al. (1998) a-InO_x

E. Bielejec and W. Wu (2002) Be





A.Yazdani and A.Kapitulnik (1995) a-MoGe



J. A. Chervenak and J. M. Valles, Jr (2000) Bi/Sb



Negative magnetoresistance



Granularity of a superconductor (2D and 3D as well)

encloses a tendency to insulating behavior (when Josephson currents are suppressed)



and leads to negative magnetoresistance (when magnetic field destroys the superconducting gap)



Superconducting grains along a current line

THEORETICAL APPROACHES

M.P.A. Fisher et al. (1990) Phenomenological description of 2D transitions based on 2*e*-bosons – vortex duality

1. Predicts scaling relations with $|B - B_{c0}|/T^{1/2n}$ as scaling variable; 2. Assumes existence of localized electron pairs.

V.M. Galitski and A.I. Larkin (2001) Superconducting fluctuations at $T << T_{c0}$ in magnetic field

The main assumptions and restrictions:1. Calculations are done in the frame of BCS theory;2. Corrections should be smaller than the conductivity itself.



 $T_{c0}t \ll 1, \quad t = T/T_{c0} \ll 1, \quad b = (B - B_{c2}(T))/B_{c2}(0) \ll 1$

$$ds = \frac{2e^2}{3p^2\hbar} \left[-\ln\frac{r}{b} - \frac{3}{2r} + y(r) + 4[ry'(r) - 1] \right] \qquad r = (1/2g)b/t$$
$$g = 1.781$$

Film Nd_{2-x}Ce_xCuO_{4+y}





d = 1000 Å c = 12 Å

$$T_{\rm C} = 11.5 \text{ K}$$
 $\Delta T = 2 \text{K}$

 $\sigma_0 = 17 \text{ e}^2/\text{h}$

Experiment

Calculations



$$R(B,T) = 1/[s_0 - a\frac{e^2}{\hbar}\ln(T) + ?s_{\rm fl}(B,T)]$$

Resistance maximum

$$R(B,T) = 1/[s_0 - a\frac{e^2}{\hbar}\ln(T) + ?s_{\rm fl}(B,T)]$$



Height of R(B) vertex



Lines $y \propto \ln x$ follow from theory by *Galitski and Larkin*

Crossover temperature





Superconducting interaction increases crossover temperature in dirty metals

 $\boldsymbol{s} + \boldsymbol{d}_{AA}\boldsymbol{s}(T_0) + \boldsymbol{ds}(B,T_0) = 0$

Scaling





Theoretical expression does not contain scaling properties, but in restricted temperature interval scaling presentation looks credible

Summary

- 1. Field and temperature dependence of superconducting fluctuations describes negative magnetoresistance of materials with moderate resistivity.
- 2. This supports the idea introduced by M.P.A. Fisher et al. about pair localization in the process of superconductor-insulator transition in high-resistive materials.
- 3. Pair localization, i.e. pair correlations between the localized electrons at the Fermi level, seems to be more general phenomenon than the idea of 2e-bosons
 vortex duality which gave rise to this contrivance.
- 4. Granularity of the superconductors leads to the same transport phenomena: to the superconductor-insulator transition and to the negative magnetoresistance, and hence granular and homogeneously disordered high-resistive materials are hardly distinguishable
- 5. Demonsjration of a scaling presentation cannot be decisive argument in favour of a specific model.